RENESAS

RBA250N04AHPF-4UA01

40V – 250A – N-channel Power MOS FET

Application : Automotive

Description

The RBA250N04AHPF-4UA01 is N-channel MOS Field Effect Transistor designed for high current switching applications.

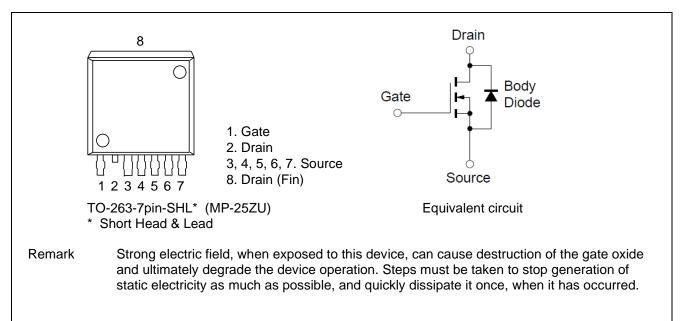
Features

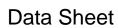
- Super low on-state resistance $R_{DS(on)} = 0.85 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 125\text{ A})$
- Low input capacitance
 Ciss = 12900pF TYP. (V_{DS} = 25 V)
- Designed for automotive application and AEC-Q101 qualified
- Pb-free (This product does not contain Pb in the external electrode)

Ordering Information

Part No.	Quantity	Shipping container
RBA250N04AHPF-4UA01#GB0	800pcs/reel	Taping

Outline





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Absolute Maximum Ratings

			(T _A =25°C)
Item	Symbol	Ratings	Unit
Drain to Source Voltage ($V_{GS} = 0 V$)	Vdss	40	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) $(T_c = 25 \text{ °C})$	ID(DC)	±250	A
Drain Current (pulse) Note1	I _{D(pulse)}	±1000	A
Total Power Dissipation (Tc = 25 °C)	P _{T1}	348	W
Total Power Dissipation (T _A = 25 °C)	P _{T2}	1.8	W
Channel Temperature	T _{ch}	175	°C
Storage Temperature	T _{stg}	-55 to 175	°C
Repetitive Avalanche Current Note2	lar	74	A
Repetitive Avalanche Energy Note3	EAR	547	mJ

Note 1. $P_W \leq 10~\mu s,~Duty~Cycle \leq 1\%$

2. $V_{GS} = 20 \rightarrow 0V$, $R_G = 25 \Omega$

3. L = 100 μH , V_DD = 20V , V_GS = 20 \rightarrow 0V, R_G = 25 Ω

Thermal Resistance

Channel to Case Thermal Resistance	Rth(ch-C)	0.43	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

Electrical Characteristics

						(T _A =25°C)
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I _{DSS}			1	μA	V _{DS} = 40 V, V _{GS} = 0 V
Gate Leakage Current	I _{GSS}			±100	nA	$V_{GS} = \pm 20 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$
Gate to Source Threshold Voltage	$V_{GS(th)}$	2.0	3.0	4.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Drain to Source On-state Resistance	R _{DS(on)} Note4		0.72	0.85	mΩ	Vgs = 10 V, Id = 125 A
Input Capacitance	C _{iss} Note5		12900	19350	pF	V _{DS} = 25 V
Output Capacitance	Coss Note5		1480	2220	pF	V _{GS} = 0 V
Reverse Transfer Capacitance	Crss Note5		680	1220	pF	f = 1 MHz
Turn-on Delay Time	t _{d(on)} Note5		45	90	ns	V _{DD} = 20 V, I _D = 125 A
Rise Time	t _r ^{Note5}		20	50	ns	Vgs = 10 V
Turn-off Delay Time	t _{d(off)} Note5		148	296	ns	$R_G = 0 \Omega$
Fall Time	t _f ^{Note5}		26	65	ns	
Total Gate Charge	Q _G Note5		245	368	nC	V _{DD} = 32 V
Gate to Source Charge	Q _{GS} Note5		56		nC	Vgs = 10 V
Gate to Drain Charge	Q _{GD} Note5		77		nC	ID = 250A
Body Diode Forward Voltage	V _{F(S-D)} Note4		0.9	1.5	V	IF = 250 A, VGS = 0 V
Reverse Recovery Time	t _{rr} ^{Note5}		94		ns	IF = 250 A, VGS = 0 V
Reverse Recovery Charge	Q _{rr} Note5		112		nC	di/dt = 100 A/ <i>µ</i> s

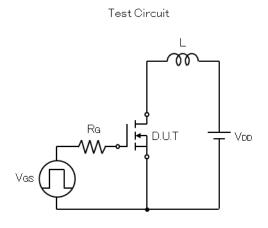
Note 4. Pulse test

Note 5. Refer value



Test Circuit

Avalanche

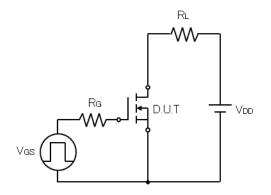


 $V_{DD} \xrightarrow{Ias} V_{BR}DSS$ $0 \xrightarrow{V_{DS}} V_{DS}$ $E_{AS} = \frac{1}{2} \cdot L \cdot I_{AS}^2 \cdot \frac{V_{DSS}}{V_{DSS} - V_{DD}}$

Waveform

Switching Time

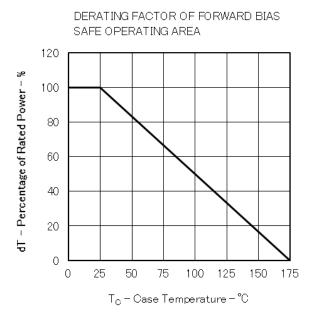




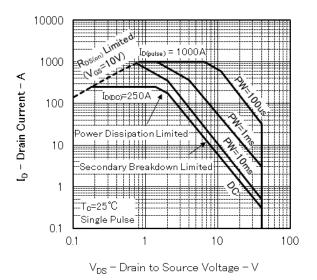
Waveform

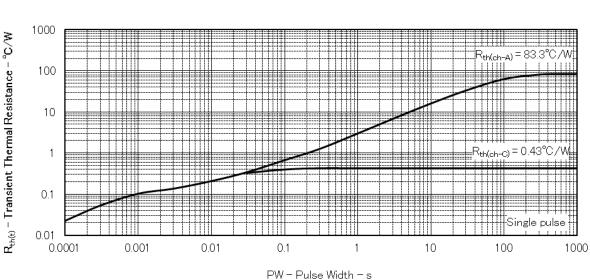


Typical Characteristics (TA = 25°C)



FORWARD BIAS SAFE OPERATING AREA

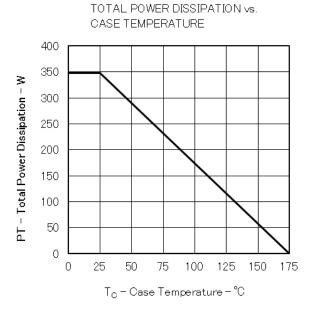


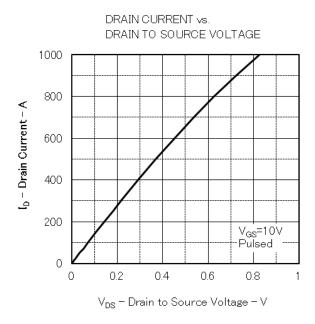


TRANSIENT THREMAL RESISTANCE vs. PULSE WIDTH

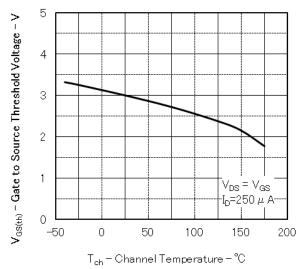
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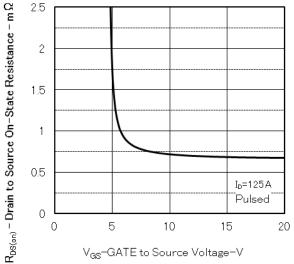




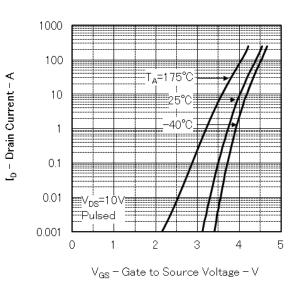




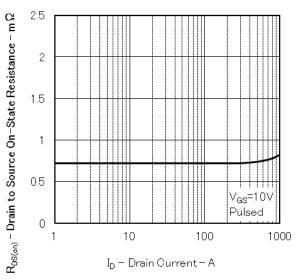




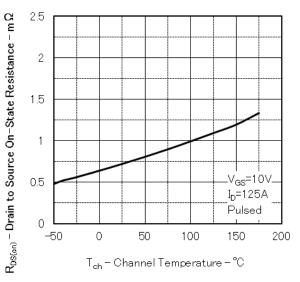




DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



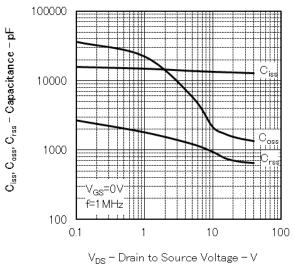
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



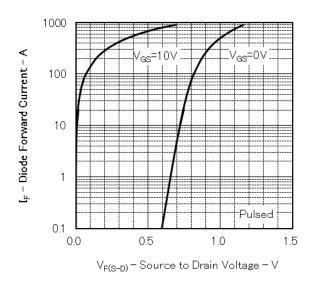
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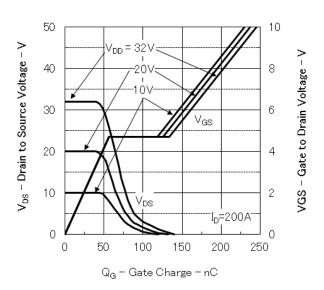
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

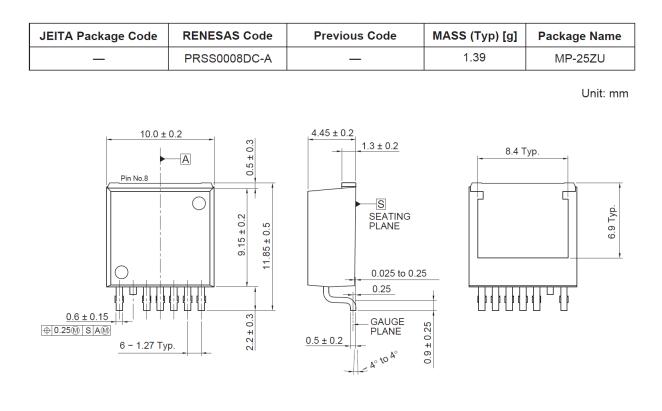


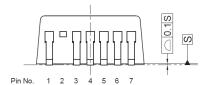
DYNAMIC INPUT/OUTPUT CHARACTERISTICS





Package Dimensions







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